

PLL Frequency Synthesizer for Electronic Tuning



Overview

The LC72133M and LC72133V are a phase-locked loop frequency synthesizer LSI circuits for use in radio tuners. It supports low-voltage (2.7 to 3.6 V) operation and can implement high-performance AM/FM tuners easily.

Functions

- High speed programmable dividers
 - FMIN: 10 to 120 MHzpulse swallower (built-in divide-by-two prescaler), $V_{DD} \ge 2.7 \text{ V}$ 10 to 130 MHzpulse swallower (built-in divide-by-two prescaler), $V_{DD} \ge 3.0 \text{ V}$
 - AMIN: 2 to 40 MHzpulse swallower
 0.5 to 10 MHzdirect division
- IF counter
 - IFIN: 0.4 to 12 MHzAM/FM IF counter
- Reference frequencies
 - Twelve selectable frequencies
 (4.5 or 7.2 MHz crystal)
 1,3,5,9,10,3.125,6.25,12.5,15,25,50 and 100 kHz

- Phase comparator
 - Dead zone control
 - Unlock detection circuit
 - Deadlock clear circuit
- Built-in MOS transistor for forming an active low-pass filter
- I/O ports
 - Dedicated output ports: 4
 - Input or output ports: 2
 - Support clock time base output
- Serial data I/O
 - Support CCB format communication with the system controller. (Compatible with LC72131)
- Operating ranges
 - Supply voltage......2.7 to 3.6 V
 - Operating temperature.....-20 to +70°C
- Package

MFP20

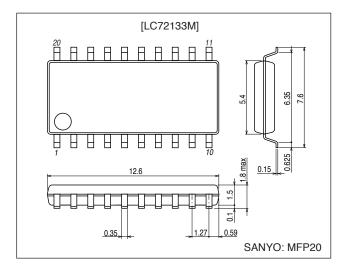
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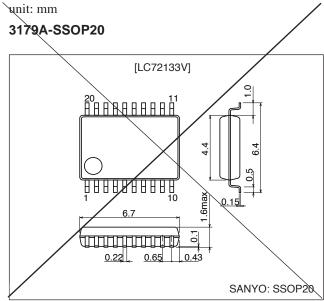
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Package Dimensions

unit: mm

3036B-MFP20





Specifications

Absolute Maximum Ratings at $Ta=25^{\circ}C,\,V_{SS}=0~V$

Parameter	Symbol	Pins	Ratings	Unit
Supply voltage	V _{DD} max	V _{DD}	-0.3 to +5.5	V
	V _{IN} 1 max	CE, CL, DI, AIN	-0.3 to +5.5	V
Maximum input voltage	V _{IN} 2 max	XIN, FMIN, AMIN, IFIN	-0.3 to V _{DD} + 0.3	V
	V _{IN} 3 max	<u>101</u> , <u>102</u>	-0.3 to +15	V
	V _O 1 max	DO	-0.3 to +5.5	V
Maximum output voltage	V _O 2 max	XOUT, PD	-0.3 to V _{DD} + 0.3	V
	V _O 3 max	BO1 to BO4, IO1, IO2, AOUT	-0.3 to +15	V
	I _O 1 max	BO1	0 to 3.0	mA
Maximum output current	I _O 2 max	AOUT, DO	0 to 6.0	mA
	I _O 3 max	BO2 to BO4, IO1, IO2	0 to 6.0	mA
Allowable news dissinction	Dd may	Ta ≤ 70°C: LC72133M	180	mW
Allowable power dissipation	Pd max	Ta ≤ 70°C: LC72133V	160	mW-
Operating temperature	Topr		-20 to +70	°C
Storage temperature	Tstg		-40 to +125	°C

Allowable Operating Ranges at $Ta = -20 \ to \ +70^{\circ}C, \ V_{SS} = 0 \ V$

Parameter	Symbol	Pins	Conditions	min	typ	max	Unit
Supply voltage	V _{DD}	V _{DD}		2.7		3.6	V
Input high lovel veltage	V _{IH} 1	CE, CL, DI		0.7 V _{DD}		5.5	V
Input high-level voltage	V _{IH} 2	ĪO1, ĪO2		0.7 V _{DD}		13	V
Input low-level voltage	V _{IL}	CE, CL, DI, $\overline{\text{IO1}}$, $\overline{\text{IO2}}$		0		0.3 V _{DD}	V
	V _O 1	DO		0		5.5	V
Output voltage	V _O 2	BO1 to BO4, IO1, IO2, AOUT		0		13	V
	f _{IN} 1	XIN	V _{IN} 1	1		8	MHz
	f _{IN} 2-1	FMIN	V _{IN} 2-1	10		90	MHz
	f _{IN} 2-2	FMIN	V _{IN} 2-2	10		120	MHz
Input frequency	f _{IN} 2-3	FMIN	V _{IN} 2-1, V _{DD} ≥ 3.0 V	10		130	MHz
	f _{IN} 3	AMIN	V _{IN} 3, SNS = 1	2		40	MHz
	f _{IN} 4	AMIN	V _{IN} 4, SNS = 0	0.5		10	MHz
	f _{IN} 5	IFIN	V _{IN} 5	0.4		12	MHz
	V _{IN} 1	XIN	f _{IN} 1	400		900	mVrms
	V _{IN} 2-1	FMIN	f _{IN} 2-1, f _{IN} 2-3	70		900	mVrms
	V _{IN} 2-2	FMIN	f _{IN} 2-2	100		900	mVrms
Input amplitude	V _{IN} 3	AMIN	f _{IN} 3, SNS = 1	70		900	mVrms
	V _{IN} 4	AMIN	f _{IN} 4, SNS = 0	70		900	mVrms
	V _{IN} 5-1	IFIN	f _{IN} 5, IFS = 1	70		900	mVrms
	V _{IN} 5-2	IFIN	f _{IN} 6, IFS = 0	100		900	mVrms
Supported crystals	Xtal	XIN, XOUT	*	4.0		8.0	MHz

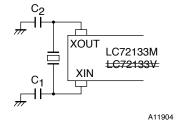
Note: * Recommended crystal oscillator CI values: CI \leq 120 Ω (For a 4.5 MHz crystal)

CI ≤ 70Ω (For a 7.2 MHz crystal)

<Sample Oscillator Circuit>

Crystal oscillator: HC-49/U (manufactured by Kinseki, Ltd.), CL = 12 pF C1 = C2 = 15 pF

The circuit constants for the crystal oscillator circuit depend on the crystal used, the printed circuit board pattern, and other items. Therefore we recommend consulting with the manufacturer of the crystal for evaluation and reliability.

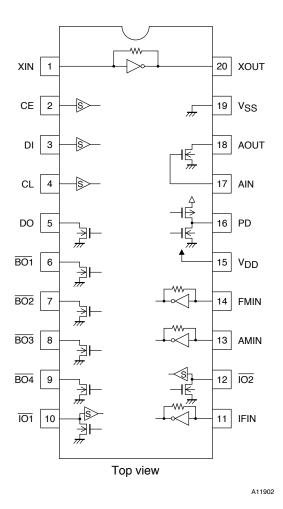


LC72133M, 72133V

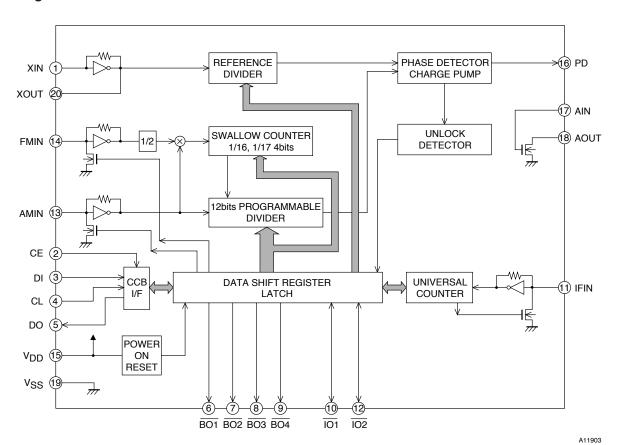
Electrical Characteristics for the Allowable Operating Ranges at $Ta=-20\ to\ +70^{\circ}C,\ V_{SS}=0\ V$

Parameter	Symbol	Pins	Conditions	min	typ	max	Unit
	Rf1	XIN			1.0		ΜΩ
	Rf2	FMIN			500		kΩ
Built-in feedback resistance	Rf3	AMIN			500		kΩ
	Rf4	IFIN			250		kΩ
	Rpd1	FMIN			200		kΩ
Built-in pull-down resistor	Rpd2	AMIN			200		kΩ
Hysteresis	V _{HIS}	CE, CL, DI, IO1, IO2			0.1 V _{DD}		V
Output high level voltage	V _{OH} 1	PD	I _O = -1 mA	V _{DD} – 1.0			V
	V _{OL} 1	PD	I _O = 1 mA			1.0	V
	V 0		I _O = 0.5 mA			0.6	V
	V _{OL} 2	BO1	I _O = 1 mA			1.2	V
0		20	I _O = 1 mA			0.25	V
Output low level voltage	V _{OL} 3	DO	$I_O = 3 \text{ mA}$			0.75	V
		<u> </u>	I _O = 1 mA			0.25	V
	V _{OL} 4	BO2 to BO4, IO1, IO2	$I_O = 5 \text{ mA}$			1.25	V
	V _{OL} 5	AOUT	I _O = 1 mA, AIN = 1.3 V			0.5	V
	I _{IH} 1	CE, CL, DI	V _I = 5.5 V			5.0	μΑ
Input high level current	I _{IH} 2	101, 102	V _I = 13 V			5.0	μΑ
	I _{IH} 3	XIN	$V_I = V_{DD}$	1.3		8	μΑ
	I _{IH} 4	FMIN, AMIN	$V_I = V_{DD}$	2.7		15	μΑ
	I _{IH} 5	IFIN	$V_I = V_{DD}$	5.4		30	μΑ
	I _{IH} 6	AIN	V _I = 5.5 V			200	nA
	I _{IL} 1	CE, CL, DI	V _I = 0 V			5.0	μΑ
	I _{IL} 2	101, 102	V _I = 0 V			5.0	μΑ
Input low level current	I _{IL} 3	XIN	V _I = 0 V	1.3		8	μΑ
input low level current	I _{IL} 4	FMIN, AMIN	V _I = 0 V	2.7		15	μΑ
	I _{IL} 5	IFIN	V _I = 0 V	5.4		30	μΑ
	I _{IL} 6	AIN	V _I = 0 V			200	nA
Output off leakage current	I _{OFF} 1	BO1 to BO4, AOUT, IO1, IO2	V _O = 13 V			5.0	μΑ
-	I _{OFF} 2	DO	V _O = 5.5 V			5.0	μΑ
High level three-state off leakage current	I _{OFFH}	PD	$V_O = V_{DD}$		0.01	200	nA
Low level three-state off leakage current	I _{OFFL}	PD	V _O = 0 V		0.01	200	nA
Input capacitance	C _{IN}	FMIN			6		pF
	I _{DD} 1	V _{DD}	Xtal = 7.2 MHz, $f_{IN}2 = 130 \text{ MHz},$ $V_{IN}2 = 70 \text{ mVrms}$		2	5	mA
Current drain	I _{DD} 2	V _{DD}	PLL block stopped (PLL INHIBIT), Xtal oscillator operating (Xtal = 7.2 MHz)		0.3		mA
	I _{DD} 3	V _{DD}	PLL block stopped Xtal oscillator stopped			30	μΑ

Pin Assignment



Block Diagram



No. 5427-5/23

Pin Functions

Symbol	Pin No.	Туре	Functions	Circuit configuration
XIN XOUT	1 20	Xtal OSC	Crystal resonator connection (4.5/7.2 MHz)	A11905
FMIN	14	Local oscillator signal input	FMIN is selected when the serial data input DVS bit is set to 1. The input frequency range is from 10 to 130 MHz. The input signal passes through the internal divide-bytwo prescaler and is input to the swallow counter. The divisor can be in the range 272 to 65535. However, since the signal has passed through the divide-by-two prescaler, the actual divisor is twice the set value. Operating FMIN input frequency conditions 10 to 90 MHz 10 to 120 MHz 10 to 130 MHz Operating powersupply voltage 2.7 to 3.6 V 2.7 to 3.6 V 3.0 to 3.6 V Operating input 70 to 900 100 to 900 70 to 900 mVrms m	A11906
AMIN	13	Local oscillator signal input	AMIN is selected when the serial data input DVS bit is set to 0. When the serial data input SNS bit is set to 1: The input frequency range is 2 to 40 MHz. The signal is directly input to the swallow counter. The divisor can be in the range 272 to 65535, and the divisor used will be the value set. When the serial data input SNS bit is set to 0: The input frequency range is 0.5 to 10 MHz. The signal is directly input to a 12-bit programmable divider. The divisor can be in the range 4 to 4095, and the divisor used will be the value set.	A11907
CE	2	Chip enable	Set this pin high when inputting (DI) or outputting (DO) serial data.	☐————————————————————————————————————
CL	4	Clock	Used as the synchronization clock when inputting (DI) or outputting (DO) serial data.	□ S A11910
DI	3	Data input	Inputs serial data transferred from the controller to the LC72133.	A11910
DO	5	Data output	Outputs serial data transferred from the LC72133 to the controller. The content of the output data is determined by the serial data DOC0 to DOC2.	A11911
V _{DD}	15	Power supply	The LC72133 power supply pin (V _{DD} = 2.7 to 3.6 V) The power on reset circuit operates when power is first applied.	

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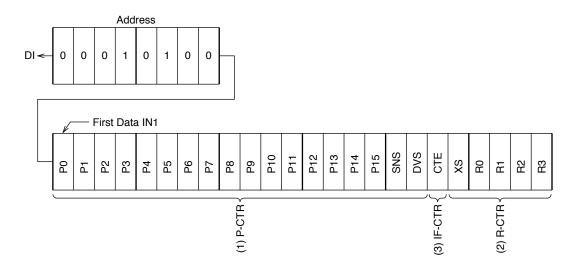
Symbol	Pin No.	Туре	Functions	Circuit configuration
V _{SS}	19	Ground	The LC72133 ground	-
BO1 BO2 BO3 BO4	6 7 8 9	Output port	Dedicated output pins The output states are determined by BO1 to BO4 bits in the serial data. Data: 0 = open, 1 = low A time base signal (8 Hz) can be output from the BO1 pin. (When the serial data TBC bit is set to 1.) Care is required when using the BO1 pin, since it has a higher on impedance than the other output ports (pins BO2 to BO4). The data = 0 (open) state is selected after the power-on reset.	A11912
101 102	10 12	I/O port	I/O dual-use pins Integration (input or output) is determined by bits IOC1 and IOC2 in the serial data. Data: 0 = input port, 1 = output port When specified for use as input ports: The state of the input pin is transmitted to the controller over the DO pin. Input state: low = 0 data value high = 1 data value When specified for use as output ports: The output states are determined by the IO1 and IO2 bits in the serial data. Data: 0 = open, 1 = low These pins function as input pins following a power on reset.	A11913
PD	16	Charge pump output	PLL charge pump output When the frequency generated by dividing the local oscillator frequency by N is higher than the reference frequency, a high level is output from the PD pin. Similarly, when that frequency is lower, a low level is output. The PD pin goes to the high impedance state when the frequencies match.	A11914
AIN AOUT	17 18	LPF amplifier transistor	The n-channel MOS transistor used for the PLL active low-pass filter.	A11915
IFIN	11	IF counter	Accepts an input in the frequency range 0.4 to 12 MHz. The input signal is directly transmitted to the IF counter. The result is output starting the MSB of the IF counter using the DO pin. Four measurement periods are supported: 4, 8, 32, and 64 ms.	A11916

Serial Data I/O Methods

The LC72133 inputs and outputs data using the Sanyo CCB (computer control bus) audio LSI serial bus format. This LSI adopts an 8-bit address format CCB.

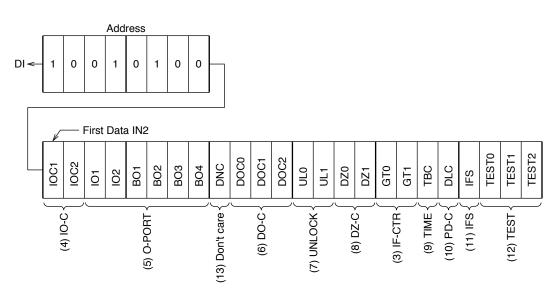
	Address											
	I/O mode	В0	B1	B2	В3	A0	A1	A2	АЗ	Function		
1	IN1 (82)	0	0	0	1	0	1	0	0	Control data input mode (serial data input) 24 data bits are input. See the "DI Control Data (serial data input) Structure" item for details on the meaning of the input data.		
2	IN2 (92)	1	0	0	1	0	1	0	0	Control data input mode (serial data input) 24 data bits are input. See the "DI Control Data (serial data input) Structure" item for details on the meaning of the input data.		
3	OUT (A2)	0	1	0	1	0	1	0	0	Data output mode (serial data output) The number of bits output is equal to the number of clock cycles. See the "DO Output Data (Serial Data Output) Structure" item for details on the meaning of the output data.		
	CE	① CL:	B2	al high			A1			A3 WFirst Data IN1/2 First Data OUT A11917		

- 1. DI Control Data (Serial Data Input) Structure
 - IN1 Mode



A11918

• IN2 Mode



A11919

LC72133M, 72133V

2. DI Control Data Functions

Programmable divider data Data that sets the programmable divider.	No.	Control block/data				Related data				
DVS and SNS, (*: don't care)		Programmable divider data	Data that	sets the p						
1		P0 to P15					The LSB char	nges depending on		
Calcalaber Cal			DVS	VS SNS LSB Divisor setting (N) Actual divisor		Actual divisor				
O			1	*	P0	272 t	to 65535	Twice the value of the setting		
Note: P0 to P3 are ignored when P4 is the LSB.				1	P0	272 t	0 65535	The value of the setting		
Selects the signal input pin (AMIN or FMIN) for the programmable divider, switches the input frequency range, (** cont care)			0	0	P4	4	to 4095	The value of the setting		
The input frequency range. (*: don't care)	(1)		Note: P0	to P3 are	ignored w	hen P4 is t	the LSB.			
Perference divider data		DVS, SNS								
Reference divider data R0 to R3 Reference frequency (fref) selection data. R0 to R3 R2			DVS	DVS SNS Input pin Input frequency range						
Reference divider data Ro to R3			1	*	FMI	N		10 to 130 MHz		
Reference divider data Reference frequency (fref) selection data. Reference frequency (ref) selection data. Reference frequency (ref) selection data. Reference frequency (ref) Reference			0	1	AMI	N		2 to 40 MHz		
Reference divider data R0 to R3										
R3 R2 R1 R0 Reference frequency (kHz)		D. (nformation.		
(2) R3 R2 R1 R0 Reference frequency (KHz)			Reference	e frequenc	y (fret) sel	ection data	a. 			
(2) (2) (3) (4) (b) (c) (c) (c) (c) (c) (c) (d) (d		HU 10 H3	R3	R2	R1	R0	Re	ference frequency (kHz)		
(2) (2) (3) (4) (4) (5) (6) (6) (6) (6) (6) (6) (6				1	_	1				
(2) (2) (3) (4) (4) (A) (A) (A) (B) (B) (B) (C) (C) (C) (C) (C						l				
(2) (2) (3) (4) (5) (6) (7) (7) (8) (8) (8) (8) (8) (9) (9) (10) (10) (11) (10				I		1				
Columbrication Colu				1		1				
Calcability						l				
1				I		1				
1			1	0	0	0		10		
1				I		I				
1	(2)					1				
1										
1				I		1				
Note: PLL INHIBIT The programmable divider block and the IF counter block are stopped, the FMIN, AMIN, and IFIN pins are set to the pull-down state (ground), and the charge pump goes to the high impedance state. XS Crystal resonator selection XS = 0: 4.5 MHz XS = 1: 7.2 MHz The 7.2 MHz frequency is selected after the power-on reset. IF counter control data CTE CTE = 0: Counter measurement start data CTE = 1: Counter reset Determines the IF counter measurement period. GT1 GT0 Measurement time (ms) Wait time (ms) 0 0 4 3 to 4 0 1 8 3 to 4 1 0 32 7 to 8 1 1 1 64 7 to 8 Note: See the "IF Counter" item for more information. (4) I/O port specification data IOC1, IOC2 Output port data BO1 to BO4, IO1, IO2 Data: 0 = open, 1 = low Note: Data that determines the output from the BO1 to BO4, IO1 and IO2 output ports Data: 0 = open, 1 = low I/OC2			1	1	1	0	PLL I	NHIBIT + Xtal OSC STOP		
The programmable divider block and the IF counter block are stopped, the FMIN, AMIN, and IFIN pins are set to the pull-down state (ground), and the charge pump goes to the high impedance state. **Year of the high impedance state.** **Crystal resonator selection XS = 0: 4.5 MHz XS = 1: 7.2 MHz The 7.2 MHz frequency is selected after the power-on reset.** **IF counter control data CTE = 1: Counter start data CTE = 0: Counter reset			1	1	1	1		PLL INHIBIT		
AMIN, and IFIN pins are set to the pull-down state (ground), and the charge pump goes to the high impedance state. Crystal resonator selection XS = 0: 4.5 MHz XS = 1: 7.2 MHz The 7.2 MHz frequency is selected after the power-on reset. IF counter control data CTE					ماداد خالما		d 4la a 117 a a	which are storing the CAINI		
Crystal resonator selection XS = 0: 4.5 MHz XS = 1: 7.2 MHz The			AMI	N, and IFIN	I pins are	set to the				
XS = 1: 7.2 MHz The 7.2 MHz frequency is selected after the power-on reset.		XS	Crystal re	sonator se	election					
The 7.2 MHz frequency is selected after the power-on reset.										
IF counter control data					ncv is sele	ected after	the power-on	reset		
CTE		IF counter control data					po non on			
(3) • Determines the IF counter measurement period. GT1 GT0 Measurement time (ms) Wait time (ms) 0			CTE = 1:	Counter st	art					
GT1 GT0 Measurement time (ms) Wait time (ms)										
(3) 0		GT0, GT1	Determin	es the IF c	ounter me	asuremen	t period.		II	FS
0	(2)		GT1	GT0	Mea	surement	time (ms)	Wait time (ms)		
1 0 32 7 to 8 1 1 1 64 7 to 8 Note: See the "IF Counter" item for more information. (4) I/O port specification data IOC1, IOC2 Output port data BO1 to BO4, IO1, IO2 Output port data BO1 to BO4, IO1, IO2 Data: 0 = open, 1 = low 1 0 32 7 to 8 7 to 8 Note: See the "IF Counter" item for more information. • Specifies the I/O direction for the bidirectional pins IO1 and IO2. Data: 0 = input mode, 1 = output mode • Data that determines the output from the BO1 to BO4, IO1 and IO2 output ports Data: 0 = open, 1 = low IOC1 IOC2	(3)		0	0		4		3 to 4		
1			0	1		8		3 to 4		
Note: See the "IF Counter" item for more information. (4) I/O port specification data IOC1, IOC2 Output port data BO1 to BO4, IO1, IO2 Data: 0 = input mode, 1 = output from the BO1 to BO4, IO1 and IO2 output ports Data: 0 = open, 1 = low IOC1 IOC2 Output port data BO1 to BO4, IO1, IO2 Note: See the "IF Counter" item for more information. Specifies the I/O direction for the bidirectional pins IO1 and IO2. Data: 0 = input mode Data that determines the output from the BO1 to BO4, IO1 and IO2 output ports IOC1 IOC2			1	0		32		7 to 8		
(4) I/O port specification data IOC1, IOC2 Output port data BO1 to BO4, IO1, IO2 • Specifies the I/O direction for the bidirectional pins IO1 and IO2. Data: 0 = input mode, 1 = output mode • Data that determines the output from the BO1 to BO4, IO1 and IO2 output ports Data: 0 = open, 1 = low IOC1 IOC2										
Output port data BO1 to BO4, IO1, IO2 Data: 0 = input mode, 1 = output mode Data: 0 = input mode, 1 = output mode Data: 0 = input mode, 1 = output mode Data: 0 = output from the BO1 to BO4, IO1 and IO2 output ports Data: 0 = open, 1 = low IOC1 IOC2										
Output port data BO1 to BO4, IO1, IO2 • Data that determines the output from the BO1 to BO4, IO1 and IO2 output ports Data: 0 = open, 1 = low IOC1 IOC2	(4)						tional pins IO1	and IO2.		
(5) BO1 to BO4, IO1, IO2 Data: 0 = open, 1 = low IOC1		· ·					BO1 to BO4.	IO1 and IO2 output ports	+	
• The data = 0 (open) state is selected after the power-on reset.	(5)						,		- 1	
			The data	= 0 (open)	state is se	elected aft	er the power-o	n reset.		002

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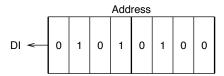
No.	Control block/data				Functions		Related data	
	DO pin control data	Data that	determine	s the DO	pin output			
	DOC0, DOC1, DOC2	DOC2	DOC1	DOC0	Ι	OO pin state		
		0 0 0 0	0 0 1 1	0 1 0 1	Open Low when the unlock s end-UC*1 Open Open	·		
		1 1 1	0 1 1	1 0 1	The IO1 pin state*2 The IO2 pin state*2 Open			
(0)		The open Note: 1.	ULO, UL1,					
(6)		DO pi	in	$ \longrightarrow $	((↓	CTE, IOC1, IOC2	
				Counter	cor	unter ③ CE: high mplete A11920		
	 ① When end-UC is set and the IF counter is started (i.e., when CTE is changed from zero to one), the DO pin automatically goes to the open state. ② When the IF counter measurement completes, the DO pin goes low to indicate the measurement completion state. ③ Depending on serial data I/O (CE: high) the DO pin goes to the open state. 2. Goes to the open state if the I/O pin is specified to be an output port. 							
		Caution: The high All with Column Col						
	Unlock detection data UL0, UL1			. ,	detection width for checking specified detection widt	ing PLL lock. h is seen as an unlocked state.		
		UL1	UL0		E detection width	Detector output		
(7)		0	0	Stopped 0		Open	DOC0, DOC1,	
(,,		1	0	±0.55 μs	:	øE is output directly øE is extended by 1 to 2 ms	DOC2	
		1	1	±1.11	<u> </u>	øE is extended by 1 to 2 ms		
		Note: In t						
	Phase comparator control data	Controls t	he phase	comparato	or dead zone.			
	DZ0, DZ1	DZ1	DZ0		Dead zo	ne mode		
		0	0	DZA				
(8)		0	1	DZB				
		1	0	DZC				
		1	1	DZD				
	Clock time base				B < DZC < DZD	mo hasa signal to be autout		
(9)	TBC Charge pump control data	from the E	3O1 pin. (E	BO1 data i	s invalid in this mode.)	ne base signal to be output	BO1	
	Charge pump control data DLC DLC DLC Charge pump output 0 Normal operation							
(10)								
(,			andlock or	Forced lo		e (Vtune) going to zero and the VCO		
		oso	illator stop	oping, dea		forcing the charge pump output to		

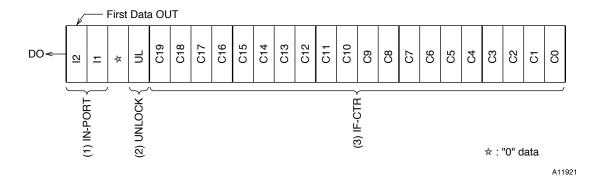
Continued from preceding page.

No.	Control block/data	Functions	Related data
(11)	IF counter control data IFS	Note that if this value is set to zero the system enters input sensitivity degradation mode, and the sensitivity is reduced to 10 to 30 mV rms. See the "IF Counter Operation" item for details.	
(12)	LSI test data TEST 0 to TEST 2	LSI test data TEST0 TEST1 Tese values must all be set to 0. TEST2 These test data are set to 0 automatically after the power-on reset.	
(13)	DNC	Don't care. This data must be set to 0.	

3. DO Output Data (Serial Data Output)

• OUT Mode

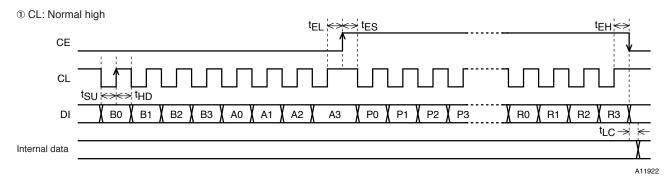




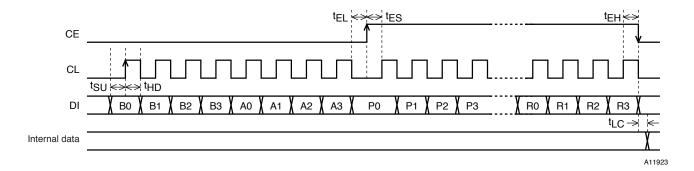
4. DO Output Data

No.	Control block/data	Functions	Related data
(1)	I/O port data I2, I1	Latched from the pin states of the IO1 and IO2 I/O ports. These values follow the pin states regardless of the input or output setting. Data is latched at the point where the circuit enters data output mode (OUT mode). I1 ← IO1 pin state High: 1 I2 ← IO2 pin state Low: 0	IOC1, IOC2
(2)	PLL unlock data UL	Latched from the state of the unlock detection circuit. UL ← 0: Unlocked UL ← 1: Locked or detection stopped mode	ULO, UL1
(3)	IF counter binary data C19 to C0	Latched from the value of the IF counter (20-bit binary counter). C19 ← MSB of the binary counter C0 ← LSB of the binary counter	CTE, GT0, GT1

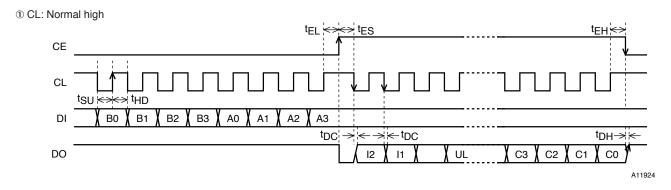
5. Serial Data Input (IN1/IN2) t_{SU} , t_{HD} , t_{EL} , t_{ES} , $t_{EH} \ge 0.75~\mu s$, $t_{LC} < 0.75~\mu s$

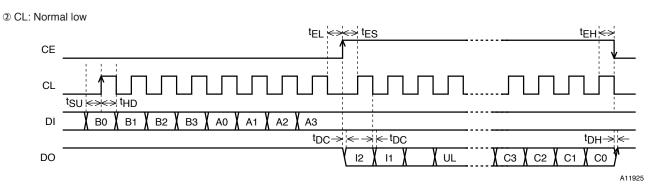


2 CL: Normal low



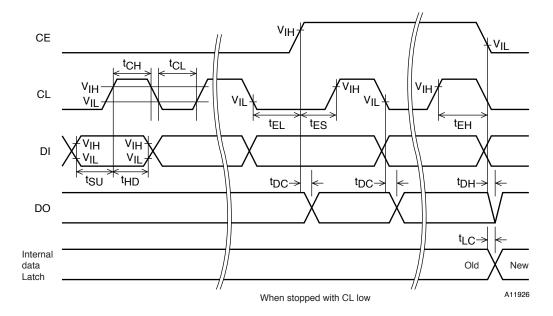
6. Serial Data Output (OUT) t_{SU} , t_{HD} , t_{EL} , t_{ES} , $t_{EH} \ge 0.75 \,\mu s$, t_{DC} , $t_{DH} < 0.35 \,\mu s$

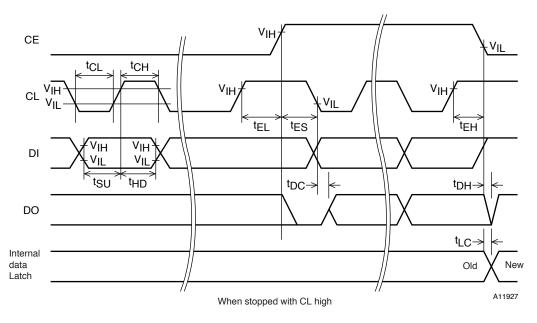




Note: Since the DO pin is an n-channel open-drain circuit, the time for the data to change (t_{DC} and t_{DH}) will differ depending on the value of the pull-up resistor and printed circuit, board capacitance.

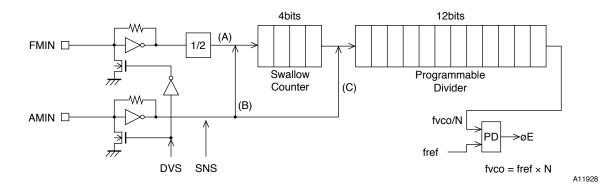
7. Serial Data Timing





Parameter	Symbol	Pins	Conditions	min	typ	max	Unit
Data setup time	t _{SU}	DI, CL		0.75			μs
Data hold time	t _{HD}	DI, CL		0.75			μs
Clock low-level time	t _{CL}	CL		0.75			μs
Clock high-level time	t _{CH}	CL		0.75			μs
CE wait time	t _{EL}	CE, CL		0.75			μs
CE setup time	t _{ES}	CE, CL		0.75			μs
CE hold time	t _{EH}	CE, CL		0.75			μs
Data latch change time	t _{LC}					0.75	μs
Data output time	t _{DC}	DO, CL	Differs depending on the value of the pull-up resistor			0.35	116
Data output time	t _{DH}	DO, CE	and the printed circuit board capacitances.			0.33	μs

Programmable Divider Structure



	DVS	SNS	Input pin	Set divisor	Actual divisor: N	Input frequency range (MHz)
Α	1	*	FMIN	272 to 65535	Twice the set value	10 to 130
В	0	1	AMIN	272 to 65535	The set value	2 to 40
С	0	0	AMIN	4 to 4095	The set value	0.5 to 10

Note: * Don't care.

- 1. Programmable Divider Calculation Examples
 - FM, 50 kHz steps (DVS = 1, SNS = *, FMIN selected)

FM RF = 80.0 MHz (IF = -10.7 MHz)

FM VCO = 69.3 MHz

PLL fref = 25 kHz (R0 to R1 = 1, R2 to R3 = 0)

69.3 MHz (FM VCO) ÷ 25 kHz (fref) ÷ 2 (FMIN: divide-by-two prescaler) = 1386 → 056A (HEX)

_		<u> </u>				5	_						(
0	1	0	1	0	1	1	0	1	0	1	0	0	0	0	0	*	1			1	1	0	0
P0	F.	P2	В	P4	P5	P6	Ь7	P8	P3	P10	P11	P12	P13	P14	P15	SNS	DVS	CTE	XS	RO	H1	R2	R3

A11929

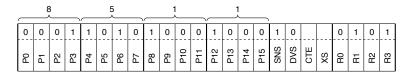
• SW, 5 kHz steps (DVS = 0, SNS = 1, AMIN high speed side selected)

SW RF = 21.75 MHz (IF = +450 kHz)

SW VCO = 22.20 MHz

PLL fref = 5 kHz (R0 = R2 = 0, R1 = R3 = 1)

22.2 MHz (SW VCO) \div 5 kHz (fref) = 4440 \rightarrow 1158 (HEX)



A11930

• MW, 10 kHz steps (DVS = 0, SNS = 0, AMIN low-speed side selected)

MW RF = 1000 kHz (IF = +450 kHz)

MW VCO = 1450 kHz

PLL fref = 10 kHz (R0 to R2 = 0, R3 = 1)

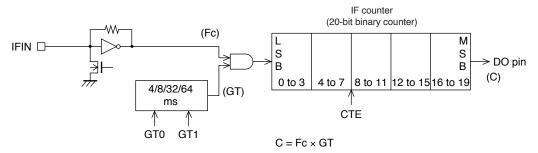
1450 kHz (MW VCO) \div 10 kHz (fref) = 145 \rightarrow 091 (HEX)

								_				_			_								
*	*	*	*	1	0	0	0	1	0	0	1	0	0	0	0	0	0			0	0	0	1
Po	Ы	P2	P3	P4	P5	P6	P7	P8	P9	P10	P11	P12	P13	P14	P15	SNS	SAO	CTE	SX	B0	R1	R2	R3

A11931

IF Counter Structure

The LC72133 IF counter is a 20-bit binary counter. The result, i.e., the counter's MSB, can be read serially from the DO pin.



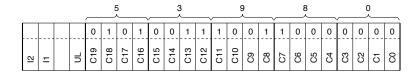
A11932

GT1	GT0	Measurement time								
GII	GIO	Measurement period (GT) (ms)	Wait time (twu) (ms)							
0	0	4	3 to 4							
0	1	8	3 to 4							
1	0	32	7 to 8							
1	1	64	7 to 8							

The IF frequency (Fc) is measured by determining how many pulses were input to an IF counter in a specified measurement period, GT.

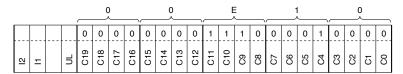
$$Fc = \frac{C}{GT}$$
 (C = Fc × GT) C: Count value (number of pulses)

- 1. IF Counter Frequency Calculation Examples
 - When the measurement period (GT) is 32 ms, the count (C) is 53980 hexadecimal (342400 decimal): IF frequency (Fc) = $342400 \div 32 \text{ ms} = 10.7 \text{ MHz}$



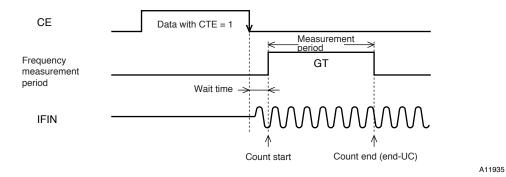
A11933

• When the measurement period (GT) is 8 ms, the count (C) is E10 hexadecimal (3600 decimal): IF frequency (Fc) = $3600 \div 8 \text{ ms} = 450 \text{ kHz}$



A11934

2. IF Counter Operation



Before starting the IF count, the IF counter must be reset in advance by setting CTE in the serial data to 0.

The IF count is started by changing the CTE bit in the serial data from 0 to 1. The serial data is latched by the LC72133 when the CE pin is dropped from high to low. The IF signal must be supplied to the IFIN pin in the period between the point the CE pin goes low and the end of the wait time at the latest. Next, the value of the IF counter at the end of the measurement period must be read out during the period that CTE is 1. This is because the IF counter is reset when CTE is set to 0.

Note: When operating the IF counter, the control microprocessor must first check the state of the IF-IC SD (station detect) signal and only after determining that the SD signal is present turn on IF buffer output and execute an IF count operation. Autosearch techniques that use only the IF counter are not recommended, since it is possible for IF buffer leakage output to cause incorrect stops at points where there is no station.

IFIN minimum input sensitivity standard

f (MHz)

IFS	$0.4 \le f < 0.5$	0.5 ≤ f < 8	8 ≤ f ≤ 12			
1: Normal mode	70 mVrms (0.5 to 5 mVrms)	70 mVrms	70 mVrms (2 to 10 mVrms)			
0: Degradation mode	100 mVrms (10 to 15 mVrms)	100 mVrms	100 mVrms (30 to 50 mVrms)			

Note: Values in parentheses are actual performance values presented as reference data.

Unlock Detection Timing

1. Unlock Detection Determination Timing

Unlocked state detection is performed in the reference frequency (fref) period (interval). Therefore, in principle, unlock determination requires a time longer than the period of the reference frequency. However, immediately after changing the divisor N (frequency) unlock detection must be performed after waiting at least two periods of the reference frequency.

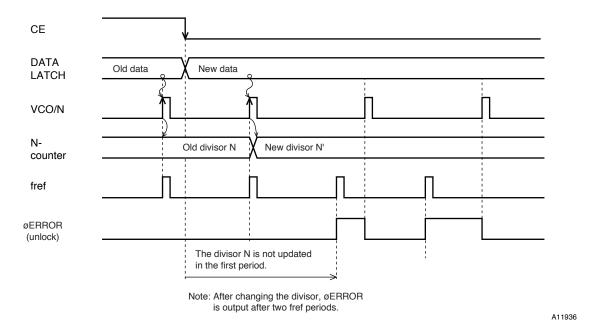


Figure 1 Unlocked State Detection Timing

For example, if fref is 1 kHz, i.e., the period is 1 ms, after changing the divisor N, the system must wait at least 2 ms before checking for the unlocked state.

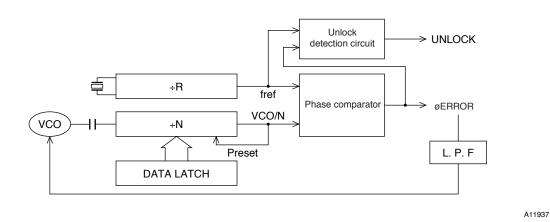
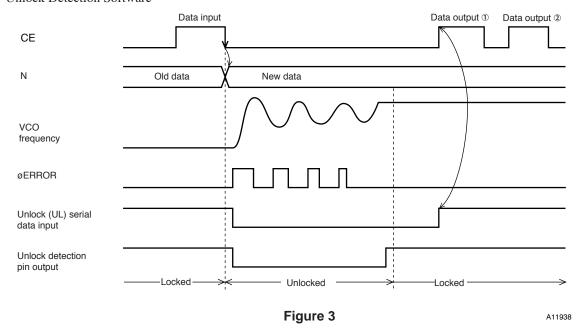


Figure 2 Circuit Structure

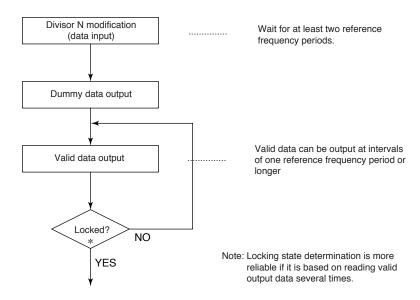
2. Unlock Detection Software



3. Unlocked State Data Output Using Serial Data Output

In the LC72133, once an unlocked state occurs, the unlocked state serial data (UL) will not be reset until a data input (or output) operation is performed. At the data output ① point in Figure 3, although the VCO frequency has stabilized (locked), since no data output has been performed since the divisor N was changed the unlocked state data remains in the unlocked state. As a result, even though the frequency has stabilized (locked), the system remains (from the standpoint of the data) in the unlocked state.

Therefore, the unlocked state data acquired at data output ①, which occurs immediately after the divisor N was changed, should be treated as a dummy data output and ignored. The second data output (data output ②) and following outputs are valid data.



Locked State Determination Flowchart

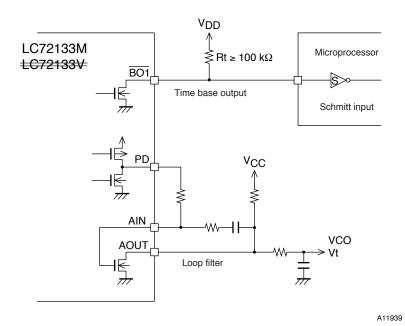
4. Directly Outputting Unlocked State Data from the DO Pin (Set by the DO pin control data)

Since the locking state (high = locked, low = unlocked) is output directly from the DO pin, the dummy data processing described in section 3 above is not required. After changing the divisor N, the locking state can be checked after waiting at least two reference frequency periods.

Clock Time Base Usage Notes

The pull-up resistor used on the clock time base output pin $(\overline{BO1})$ should be at least 100 k Ω . Also, to prevent chattering we recommend using a Schmitt input at the controller (microprocessor) that receives this signal.

This is to prevent degrading the VCO C/N characteristics when a loop filter is formed using the built-in low-pass filter transistor. Since the clock time base output pin and the low-pass filter have a common ground internal to the IC, it is necessary to minimize the time base output pin current fluctuations and to suppress their influence on the low-pass filter.



Other Items

1. Notes on the Phase Comparator Dead Zone

DZ1	DZ0	Dead zone mode	Charge pump	Dead zone
0	0	DZA	ON/ON	0 s
0	1	DZB	ON/ON	−0 s
1	0	DZC	OFF/OFF	+0 s
1	1	DZD	OFF/OFF	+ +0 s

Since correction pulses are output from the charge pump even if the PLL is locked when the charge pump is in the ON/ON state, the loop can easily become unstable. This point requires special care when designing application circuits.

The following problems may occur in the ON/ON state.

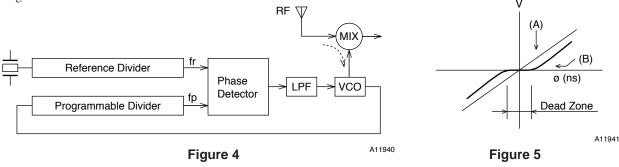
- Side band generation due to reference frequency leakage
- Side band generation due to both the correction pulse envelope and low frequency leakage

Schemes in which a dead zone is present (OFF/OFF) have good loop stability, but have the problem that acquiring a high C/N ratio can be difficult. On the other hand, although it is easy to acquire a high C/N ratio with schemes in which there is no dead zone, it is difficult to achieve high loop stability. Therefore, it can be effective to select DZA or DZB, which have no dead zone, in applications which require an FM S/N ratio in excess of 90 to 100 dB, or in which an increased AM stereo pilot margin is desired. On the other hand, we recommend selecting DZC or DZD, which provide a dead zone, for applications which do not require such a high FM signal-to-noise ratio and in which either AM stereo is not used or an adequate AM stereo pilot margin can be achieved.

Dead Zone

The phase comparator compares fp to a reference frequency (fr) as shown in Figure 4. Although the characteristics of this circuit (see Figure 5) are such that the output voltage is proportional to the phase difference \emptyset (line A), a region (the dead zone) in which it is not possible to compare small phase differences occurs in actual ICs due to internal circuit delays and other factors (line B). A dead zone as small as possible is desirable for products that must provide a high S/N ratio.

However, since a larger dead zone makes this circuit easier to use, a larger dead zone is appropriate for popularly-priced products. This is because it is possible for RF signals to leak from the mixer to the VCO and modulate the VCO in popularly-priced products in the presence of strong RF inputs. When the dead zone is narrow, the circuit outputs correction pulses and this output can further modulate the VCO and generate beat frequencies with the RF signal.



2. Notes on the FMIN, AMIN, and IFIN Pins

Coupling capacitors must be placed as close as possible to their respective pin. A capacitance of about 100 pF is desirable. In particular, if a capacitance of 1000 pF or over is used for the IF pin, the time to reach the bias level will increase and incorrect counting may occur due to the relationship with the wait time.

3. Notes on IF Counting → SD must be used in conjunction with the IF counting time When using IF counting, always implement IF counting by having the microprocessor determine the presence of the IF-IC SD (station detect) signal and turn on the IF counter buffer only if the SD signal is present. Schemes in which auto-searches are performed with only IF counting are not recommended, since they can stop at points where there is no signal due to leakage output from the IF counter buffer.

4. DO Pin Usage Techniques

In addition to data output mode times, the DO pin can also be used to check for IF counter count completion and for unlock detection output. Also, an input pin state can be output unchanged through the DO pin and input to the controller.

5. Power Supply Pins

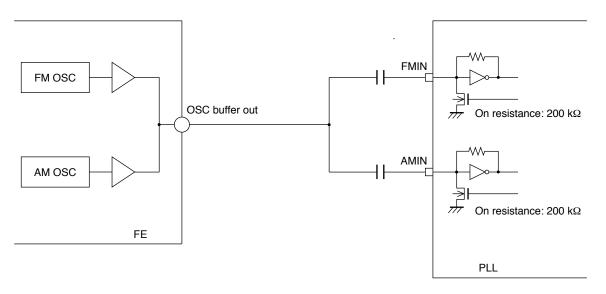
A capacitor of at least 2000 pF must be inserted between the power supply V_{DD} and V_{SS} pins for noise exclusion. This capacitor must be placed as close as possible to the V_{DD} and V_{SS} pins.

6. VCO setup

Applications must be designed so that the VCO (local oscillator) does not stop, even if the control voltage (Vtune) goes to 0V. If it is possible for the oscillator to stop, the application must use the control data (DLC) to temporarily force Vtune to V_{CC} to prevent the deadlock from occuring. (Deadlock clear circuit)

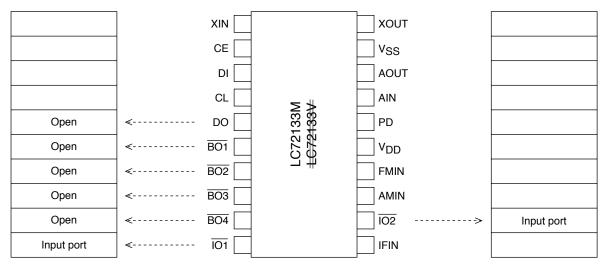
7. Front end connection example

Since this product is designed with the relatively high resistance of 200 k Ω for the pull-down (on) resistors built in to the FMIN and AMIN pins, a common AM/FM local oscillator buffer can be used as shown in the following circuit.



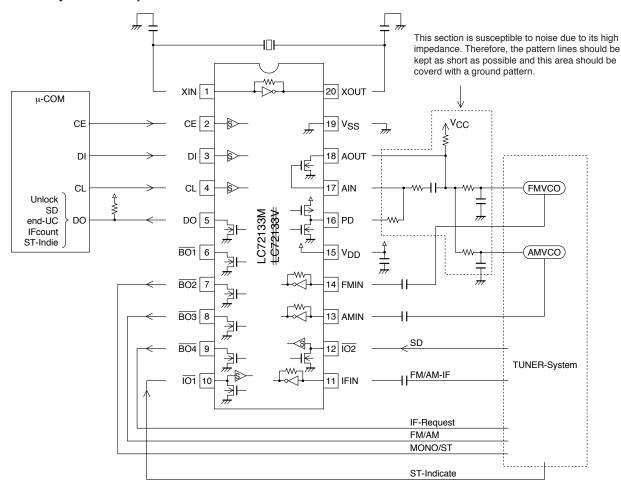
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Pin States After the Power ON Reset



A11943

Application System Example



A11944

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